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### First Principles Study of Surface States and Tetragonal Distortion in Half Metals

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### Background

- ✓ Research on magnetic materials for potential applications in spin-based electronics: one of the most active fields in academia and industry.
- $\checkmark$  High degree of spin polarization wanted in spintronics.
- $\checkmark$  Spintronics an emerging technology utilizing a spin degree of freedom.  $\checkmark$  Various mechanisms alter degree of spin polarization – mechanical strain, structural disorder, temperature, termination surface/interface in thin film multilayer geometry, etc.
- ✓ Magnetic materials that conduct electrons of only one spin are called half-metals, and have a great potential in spintronic devices.

## Motivation and Methods

- $\triangleright$  Ideal candidate for spintronics room temperature half-metal.
- > Heusler compounds attractive because of high Curie temperature.
- > Ti<sub>2</sub>MnAl<sub>0.5</sub>Sn<sub>0.5</sub>: half-metallic electronic structure in bulk geometry.
- > But is it half-metallic in thin-film geometry?
- ✓ Detrimental effect of surfaces on half-metallicity reported in the past. ✓ DFT – Vienna Ab Initio Simulation Package (VASP).
- ✓ Computations performed at the Department of Physics computing facilities (20-node Beowulf cluster), UNI, and at the Pittsburgh Supercomputing Center – Bridges.



## Half-metallic surfaces in thin-film Ti<sub>2</sub>MnAl<sub>0.5</sub>Sn<sub>0.5</sub>

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- *Phys.: Condens. Matter* **31**, 055801 (2019).
- Lett. 108, 141901 (2016).

# $Ti_2MnAl_{0.5}Sn_{0.5}$ – bulk half-metal <sup>└</sup> regular, a=6.289 Å



## **Conclusions and References**

 $\checkmark$  Ti<sub>2</sub>MnAl<sub>0.5</sub>Sn<sub>0.5</sub>: half-metal in bulk geometry: metal for spin-up, semiconductor spin-down states. ✓ Six termination configurations analyzed: for 4 of them, energy states emerge in the minority-spin band gap  $\checkmark$  Two termination surfaces preserve half-metallic properties of this material.

✓ Surface states in part due to Al, and its hybridization with other atoms. Atomic relaxations have negligible effect on surface HM. ✓ "Half-metallic surfaces in thin-film Ti<sub>2</sub>MnAl<sub>0.5</sub>Sn<sub>0.5</sub>", Sam Prophet, Rishabh Dalal, Parashu R Kharel, and Pavel V Lukashev, J.

 $\checkmark$  "Investigation of spin-gapless semiconductivity and half-metallicity in Ti<sub>2</sub>MnAl-based compounds", P. Lukashev, P. Kharel, S. Gilbert, B. Staten, N. Hurley, R. Fuglsby, Y. Huh, S. Valloppilly, W. Zhang, K. Yang, R. Skomski, and D. J. Sellmyer; Appl. Phys.



✓ Replacement of 50% of Al with Sn results in increase of lattice constant. ✓ Inverted cubic structure is ground state.  $\checkmark$  Ti<sub>2</sub>MnAl<sub>0.5</sub>Sn<sub>0.5</sub> – half-metal in bulk geometry.

✓ Strain induced half-metallic transition,  $\checkmark$  For applications thin films are needed. ✓ Is it half-metallic in thin-fil geometry?